- ZENER DIODES
- •LEADLESS PACKAGE FOR SURFACE MOUNT
- DOUBLE PLUG CONSTRUCTION
- METALLURGICALLY BONDED

BZV55 C2V4 thru BZV55 C75

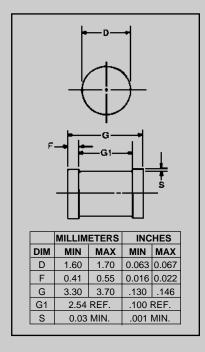
MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C Storage Temperature: -65°C to +175°C Power Derating: 3.33 mW / °C above +50°C Forward Voltage: @ 200mA: 1.1 Volts maximum

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified.

TYPE	ZENER VOLTAGE (NOTE 1) Vz @ I ZT			MAXIMUM DIFFERENTIAL RESISTANCE Fdiff ^{@ I} Z		MAXIMUM REVERSE CURRENT I _R @ V _R	
	VO MIN	LTS MAX	mA	OHMS	mA	μΑ	VOLTS
BZV55 C2V4 BZV55 C2V7 BZV55 C3V0 BZV55 C3V3 BZV55 C3V6	2.2 2.5 2.8 3.1 3.4	2.6 2.9 3.2 3.5 3.8	5 5 5 5 5	100 100 95 95 90	5 5 5 5 5	50 20 10 5	1 1 1 1
BZV55 C3V9	3.7	4.1	5	90	5	3	1
BZV55 C4V3	4.0	4.6	5	90	5	3	1
BZV55 C4V7	4.4	5.0	5	80	5	3	2
BZV55 C5V1	4.8	5.4	5	60	5	2	2
BZV55 C5V6	5.2	6.0	5	40	5	1	2
BZV55 C6V2	5.8	6.6	5	10	5	3	4
BZV55 C6V8	6.4	7.2	5	15	5	2	4
BZV55 C7V5	7.0	7.9	5	15	5	1	5
BZV55 C8V2	7.7	8.7	5	15	5	.700	5
BZV55 C9V1	8.5	9.6	5	15	5	.500	6
BZV55 C10	9.4	10.6	5	20	5	.200	7
BZV55 C11	10.4	11.6	5	20	5	.100	8
BZV55 C12	11.4	12.7	5	25	5	.100	8
BZV55 C13	12.4	14.1	5	30	5	.100	8
BZV55 C15	13.8	15.6	5	30	5	.050	10.5
BZV55 C16	15.3	17.1	5	40	5	.050	11.2
BZV55 C18	16.8	19.1	5	45	5	.050	12.6
BZV55 C20	18.8	21.2	5	55	5	.050	14.0
BZV55 C22	20.8	23.3	5	55	5	.050	15.4
BZV55 C24	22.8	25.6	5	70	5	.050	16.8
BZV55 C27 BZV55 C30 BZV55 C33 BZV55 C36 BZV55 C39	25.1 28.0 31.0 34.0 37.0	28.9 32.0 35.0 38.0 41.0	2 2 2 2 2 2	80 80 80 90 130	2 2 2 2 2 2	.050 .050 .050 .050 .050	18.9 21.0 23.1 25.2 27.3
BZV55 C43 BZV55 C47 BZV55 C51 BZV55 C56 BZV55 C62	40.0 44.0 48.0 52.0 58.0	46.0 50.0 54.0 60.0 66.0	2 2 2 2 2 2	150 170 180 200 215	2 2 2 2 2 2	.050 .050 .050 .050 .050	30.1 32.9 35.7 39.2 43.4
BZV55 C68	64.0	72.0	2	240	2	.050	47.6
BZV55 C75	70.0	79.0	2	255	2	.050	52.2

NOTE 1 Nominal Zener voltage is measured with the device junction in thermal equilibrium at an ambient temperature of $25^{\circ}\text{C} \pm 3^{\circ}\text{C}$.



DESIGN DATA

CASE: DO-213AA, Hermetically sealed glass case. (MELF, SOD-80, LL34)

LEAD FINISH: Tin / Lead

THERMAL RESISTANCE: (R_{OJEC}): 100 PC/W maximum at L = 0 inch

THERMAL IMPEDANCE: (ZOJX): 35

ÞC/W maximum

POLARITY: Diode to be operated with the banded (cathode) end positive.

MOUNTING SURFACE SELECTION:

The Axial Coefficient of Expansion (COE) Of this Device is Approximately +6PPM/°C. The COE of the Mounting Surface System Should Be Selected To Provide A Suitable Match With This Device.

